## FAIRCHILD

SEMICONDUCTOR

## FSTU32160A 16-Bit to 32-Bit Multiplexer/Demultiplexer Bus Switch with –2V Undershoot Protection

**Features** 

■ Low I<sub>CC</sub>.

■ Undershoot hardened to -2V (A and B Ports).

Minimal propagation delay through the switch.

 $\blacksquare$  4 $\Omega$  switch connection between two ports.

Control inputs compatible with TTL level.

See Applications Note AN-5008 for details

Zero bounce in flow-through mode.

#### **General Description**

The Fairchild Switch FSTU32160A is a 16-bit to 32-bit high-speed CMOS TTL-compatible multiplexer/demultiplexer bus switch. The low on resistance of the switch allows inputs to be connected to outputs without adding propagation delay or generating additional ground bounce noise.

The device can be used in applications where two buses need to be addressed simultaneously. The FSTU32160A is designed so that the A Port demultiplexes into B<sub>1</sub> or B<sub>2</sub> or both. The A and B Ports are "undershoot hardened" with UHC<sup>TM</sup> protection to support an extended range to 2.0V below ground. Fairchild's integrated Undershoot Hardened Circuit, UHC senses undershoot at the I/O's, and responds by preventing voltage differentials from developing and turning on the switch.

Two select (SEL<sub>1</sub>, SEL<sub>2</sub>) inputs provide switch enable control. When SEL<sub>1</sub>, SEL<sub>2</sub> are HIGH, the device precharges the B Port to a selectable bias voltage (Bias V) to minimize live insertion noise.

#### **Ordering Code:**

Order Number	Package Number	Package Description
FSTU32160AMTD	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

UHC<sup>™</sup> is a trademark of Fairchild Semiconductor Corporation.

June 1999 Revised March 2000

# FSTU32160A

Connection Diagram					
18,	1 56   2 55   3 54   4 53   5 52   6 51   7 50   8 49   9 48   10 47   11 46   12 45   13 44   14 43   15 42   16 41   17 40   18 39   19 38   20 37   21 36   22 35   23 34	$ \begin{array}{c} 1A \\ 1B_2 \\ 2B_2 \\ 3A \\ 3B_2 \\ 4B_2 \\ 5A \\ 5B_2 \\ 6B_2 \\ 7A \\ 7B_2 \\ 6B_2 \\ 7A \\ 7B_2 \\ 9B_2 \\ 10B_2 \\ 11B_2 \\ 12B_2 \\ 11B_2 \\ 11B_2 \\ 12B_2 \\ 11B_2 \\$			
16B <sub>1</sub> — 16A — BIAS V <sub>1</sub> — SEL <sub>1</sub> —	25 32 26 31 27 30 28 29	— 15B <sub>2</sub> — 16B <sub>2</sub> — BIAS V <sub>2</sub> — SEL <sub>2</sub>			

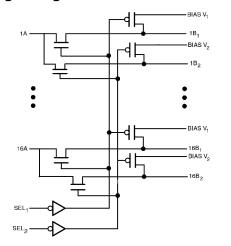
## **Pin Descriptions**

Pin Name	Description
SEL <sub>1</sub> , SEL <sub>2</sub>	Select Inputs
A	Bus A
B <sub>1</sub> , B <sub>2</sub>	Bus B

## Truth Table

Inp	outs	Function
SEL <sub>1</sub>	SEL <sub>2</sub>	Function
L	Н	$x A = x B_1$
н	L	$x A = x B_2$
L	L	$x A = x B_1 and x B_2$
н	Н	$x B_1, x B_2 = BiasV$

## Logic Diagram



#### Absolute Maximum Ratings(Note 1)

Supply Voltage (V <sub>CC</sub> ) DC Switch Voltage (V <sub>S</sub> ) (Note 2)	-0.5V to +7.0V -2.0V to +7.0V
BiasV Voltage Range DC Input Control Pin Voltage	-0.5V to +7.0V
(V <sub>IN</sub> ) (Note 3)	-0.5V to +7.0V
DC Input Diode Current ( $I_{IK}$ ) $V_{IN} < 0V$	–50 mA
DC Output Current (I <sub>OUT</sub> )	128 mA
DC V <sub>CC</sub> /GND Current (I <sub>CC</sub> /I <sub>GND</sub> )	+/- 100 mA
Storage Temperature Range (T <sub>STG</sub> )	–65°C to +150 °C

#### Recommended Operating Conditions (Note 4)

Power Supply Operating ( $V_{CC}$ )	4.0V to 5.5V
Precharge Supply (BiasV)	1.5 to $V_{CC}$
Input Voltage (V <sub>IN</sub> )	0V to 5.5V
Output Voltage (V <sub>OUT</sub> )	0V to 5.5V
Input Rise and Fall Time $(t_r, t_f)$	
Switch Control Input	0nS/V to 5nS/V
Switch I/O	0nS/V to DC

FSTU32160A

Free Air Operating Temperature (T\_A)  $-40\ ^\circ C$  to +85  $^\circ C$ 

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum rating. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2:  $\mathsf{V}_S$  is the voltage observed/applied at either the A or B Ports across the switch.

**Note 3:** The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.

Note 4: Unused control inputs must be held HIGH or LOW. They may not float.

## **DC Electrical Characteristics**

			$T_A = -40 \ ^\circ C \ to \ +85 \ ^\circ C$				
Symbol	Parameter	V <sub>cc</sub>	Min	Тур	Max	Units	Conditions
		(V)		(Note 5)			
V <sub>IK</sub>	Clamp Diode Voltage	4.5			-1.2	V	$I_{IN} = -18 \text{mA}$
V <sub>IH</sub>	HIGH Level Input Voltage	4.0-5.5	2.0			V	
V <sub>IL</sub>	LOW Level Input Voltage	4.0-5.5			0.8	V	
I <sub>I</sub>	Input Leakage Current	5.5			±1.0	μA	$0 \le V_{IN} \le 5.5V$
		0			10	μA	V <sub>IN</sub> = 5.5V
I <sub>O</sub>	Output Current	4.5	0.25			mA	BiasV = 2.4V
							$B_X = 0$
I <sub>OZH</sub> , I <sub>OZL</sub>	OFF-STATE Leakage Current	5.5			±1.0	μA	$0 \le A \le V_{CC}, V$
							$BiasV_1 = BiasV_2 = 5.5V$
I <sub>OZH</sub> , I <sub>OZL</sub>	OFF-STATE Leakage Current	5.5			±1.0	μA	$0 \le B \le V_{CC}, V$
							$BiasV_1 = BiasV_2 = Floating$
R <sub>ON</sub>	Switch On Resistance	4.5		4	7	Ω	$V_{IN} = 0V, I_{IN} = 64 \text{ mA}$
	(Note 6)	4.5		4	7	Ω	$V_{IN} = 0V, I_{IN} = 30 \text{ mA}$
		4.5		8	14	Ω	$V_{IN} = 2.4V, I_{IN} = 15 \text{ mA}$
		4.0		11	20	Ω	$V_{IN} = 2.4V, I_{IN} = 15 \text{ mA}$
I <sub>CC</sub>	Quiescent Supply Current	5.5			3	μA	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$
$\Delta I_{CC}$	Increase in I <sub>CC</sub> per Input	5.5			2.5	mA	One input at 3.4V
							Other inputs at V <sub>CC</sub> or GND
I <sub>BIAS</sub>	Bias Pin Leakage Current	5.5			±1.0	μA	$SEL_1$ , $SEL_2 = 0V$
							$B_X = 0V$ , $BiasV_X = 5.5V$
V <sub>IKU</sub>	Voltage Undershoot	5.5			-2.0	V	$0.0 \text{ mA} \ge I_{IN} \ge -50 \text{ mA}$
							$SEL_1$ , $SEL_2 = 5.5V$

Note 5: Typical values are at  $V_{CC}$  = 5.0V and  $T_A$  = +25°C

Note 6: Measured by the voltage drop between A and B pins at the indicated current through the switch. On resistance is determined by the lower of the voltages on the two (A or B) pins.

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## **AC Electrical Characteristics**

	Parameter		$T_A = -40$ °C to +85 °C, C <sub>L</sub> = 50 pF, RU= RD = 500 $\Omega$				Ormalitiens	
Symbol	Parameter	$V_{CC} = 4$	$V_{CC}=4.5-5.5V$		$V_{CC} = 4.0V$		Conditions	Figure No.
		Min	Max	Min	Max			
t <sub>PHL</sub> , t <sub>PLH</sub>	A or B, to B or A (Note 7)		0.25		0.25	ns	V <sub>I</sub> = OPEN	Figure 2 Figure 3
t <sub>PZH</sub>	Output Enable Time, SEL to A, B	0.5	4.0		4.5	ns	V <sub>I</sub> = OPEN for t <sub>PZH</sub> BiasV = GND	Figure 2 Figure 3
t <sub>PZL</sub>	Output Enable Time, SEL to A, B	1.0	4.8		5.5	ns	$V_I = 7V$ for $t_{PZL}$ BiasV = 3V	Figure 2 Figure 3
t <sub>PHZ</sub>	Output Disable Time, SEL to A, B	1.0	5.9		6.9	ns	V <sub>I</sub> = Open for t <sub>PHZ</sub> BiasV = GND	Figure 2 Figure 3
t <sub>PLZ</sub>	Output Disable Time,	1.0	7.4		7.0	ns	$V_I = 7V$ for $t_{PLZ}$ BiasV = 3V	Figure 2 Figure 3

Note 7: This parameter is guaranteed by design but is not tested. The bus switch contributes no propagation delay other than the RC delay of the typical On resistance of the switch and the 50pF load capacitance, when driven by an ideal voltage source (zero output impedance).

#### Capacitance (Note 8)

Symbol	Parameter	Тур	Max	Units	Conditions
C <sub>IN</sub>	Control pin Input Capacitance	4		pF	$V_{CC} = 5.0V$
CI/O OFF	Input/Output Capacitance "OFF State"	8		pF	$V_{CC} = 5.0V$ , Switch OFF

Note 8:  $T_A = +25^{\circ}C$ , f = 1 Mhz, Capacitance is characterized but not tested.

## Undershoot Characteristic (Note 9)

Symbol	Parameter	Min	Тур	Max	Units	Conditions
V <sub>OUTU</sub>	Output Voltage During Undershoot	2.5	V <sub>OH</sub> – 0.3		V	Figure 1
Note 9. This	is intended to characterize the device's prote	octive canabilities	by maintaining	output signal inte	arity during on in	oput transient voltage undershoot

Note 9: This is intended to characterize the device's protective capabilities by maintaining output signal integrity during an input transient voltage under event.

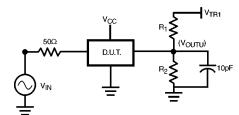
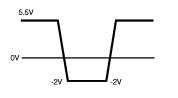


FIGURE 1.

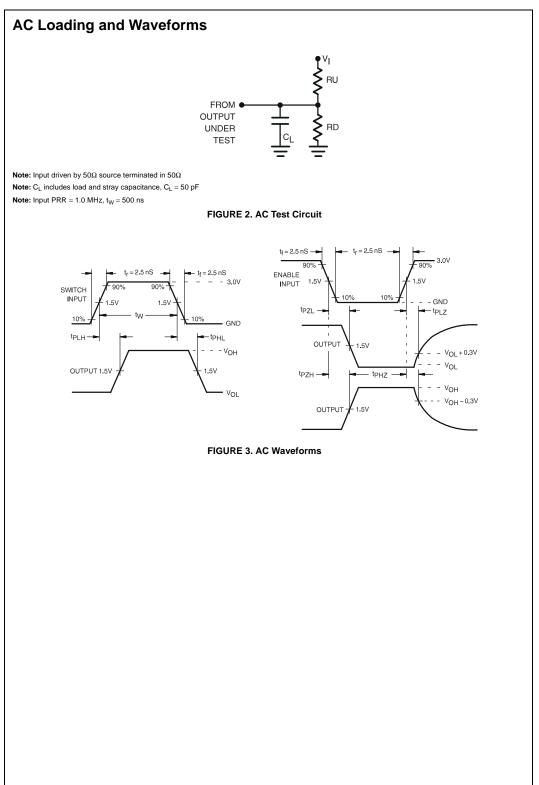
#### **Device Test Conditions**

Parameter	Value	Units
V <sub>IN</sub>	See Waveform	V
R <sub>1</sub> - R <sub>2</sub>	100K	Ω
V <sub>TRI</sub>	11.0	V
V <sub>CC</sub>	5.5	V

#### Transient Input Voltage (V<sub>IN</sub>) Waveform

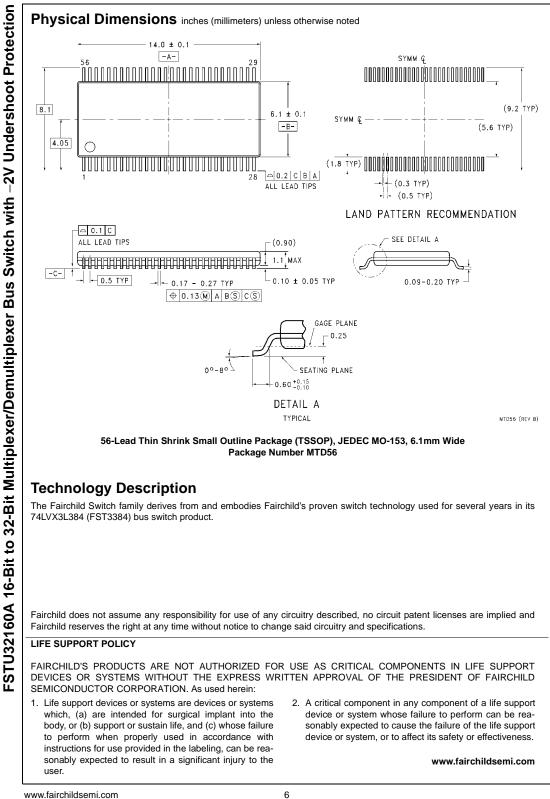


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